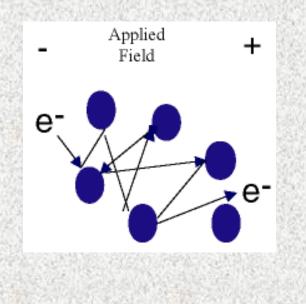
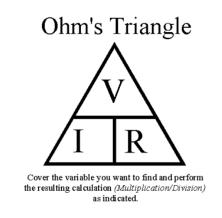
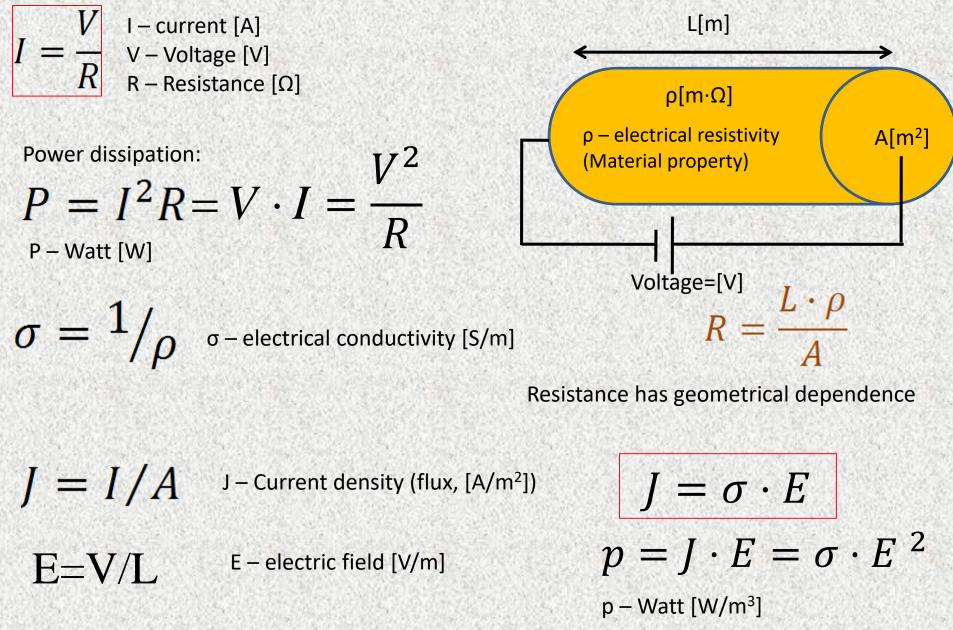
Electronic properties



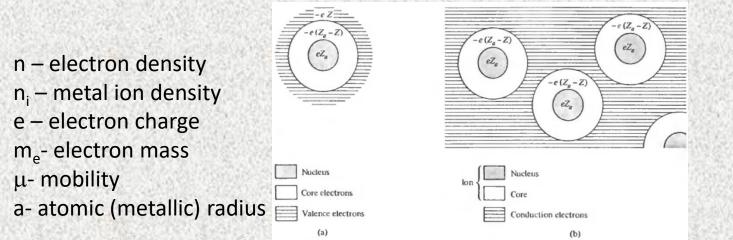


Primer in Materials Spring 2021

Ohm's low



Drude model



Assumptions

•All atoms gives their valance electron to the 'sea of electron'

e

- •Ion are localized, Electron moves in straight lines between collisions
- Relaxation time: τ time between collisions

$$\sigma = \mu n e \qquad \sigma = \frac{n e^2 \tau}{m_e} \quad \text{The electrical conductivity related to} \\ \mu = \frac{e \tau}{m_e} \qquad \tau = \frac{m_e}{\rho n e^2} = \frac{1}{n_e \pi a^2} \cdot \sqrt{\frac{m_e}{3KT}}$$

V 3K I

pne-

Typical relaxation times

Table 1.2 ELECTRICAL RESISTIVITIES OF SELECTED ELEMENTS ^a					Table 1.3 DRUDE RELAXATION TIMES IN UNITS OF 10 ⁻¹⁴ SECOND ^a			
LEMENT	77 K	273 K	373 K	$(\rho/T)_{373 \text{ K}}$	ELEMENT	77 K	273 K	373 k
				$(\rho/T)_{273 \text{ K}}$	Li	7.3	0.88	0.61
Li	1.04	8.55	12.4	1.06	Na	17	3.2	0.01
Na	0.8	4.2	Melted	56 S	К	18	4.1	
ĸ	1.38	6.1	Melted	8	Rb	14	2.8	
Rb	2.2	11.0	Melted		Cs	8.6		
Cs	4.5	18.8	Melted	12			2.1	1211421
Cu	0.2	1.56	2.24	1.05	Cu	21	2.7	1.9
Ag	0.3	1.51	2.13	1.03	Ag	20	4.0	2.8
Au	0.5	2.04	2.84	1.02	Au	12	3.0	2.1
Be	0.02	2.8	5.3	1.39	Be		0.51	0.27
Mg	0.62	3.9	5.6	1.05	Mg	6.7	1.1	0.74
Ca Sr	7	3.43 23	5.0	1.07	Ca		2.2	1.5
Ba	17	60		100	Sr	1.4	0.44	
Nb	3.0	15.2	19.2	0.92	Ba	0.66	0.19	
Fe	0.66	8.9	14.7	1.21	Nb	2.1	0.42	0.33
Zn	1.1	5.5	7.8	1.04	Fe	3.2	0.42	0.14
Cd	1.6	6.8			Zn	2.4		
Hg	5.8	Melted	Melted		Cd		0.49	0.34
AI	0.3	2.45	3.55	1.06		2.4	0.56	
Ga	2.75	13.6	Melted	20	Hg	0.71		
In	1.8	8.0	12.1	1.11	Ai	6.5	0.80	0.55
TI	3.7	15	22.8	1.11	Ga	0.84	0.17	
Sn	2.1	10.6	15.8	1.09	In	1.7	0.38	0.25
Pb	4.7	19.0	27.0	1.04	П	0.91	0.22	0.15
Bi	35	107	156	1.07	Sn	1.1	0.23	0.15
Sb	8	39	59	1.11	Pb	0.57	0.14	0.09
Desistivities	in milene has seen	imatern and simo	-+ 77 V (++ - 1 - 1)	1 . CV . / A	Bi	0.072		
Resistivities	in microhm cent	imeters are given:	at 77 K (the boilin			0.072	0.023	0.01

" Resistivities in microhm centimeters are given at 77 K (the boiling point of liquid nitrogen at atmospheric pressure), 273 K, and 373 K. The last column gives the

approximate linear temperature

 $[\mu\Omega\cdot cm] = 1X10^{-8}[\Omega\cdot m]$ ture.

r

d

Summer of Physical and Chemical Constants, Longmans Green, London, 1966. " Relaxation times are calculated from the data in Tables 1.1 and 1.2, and Eq. (1.8). The slight temperature dependence of n is ignored.

0.055

0.036

0.27

Sb

Drift velocity

 V_{th} – thermal velocity E – electric field V_{drift} – drift velocity

$$V_{th} = \sqrt{\frac{3KT}{m_e}}$$

$$J = \sigma E = n e v_{drift}$$

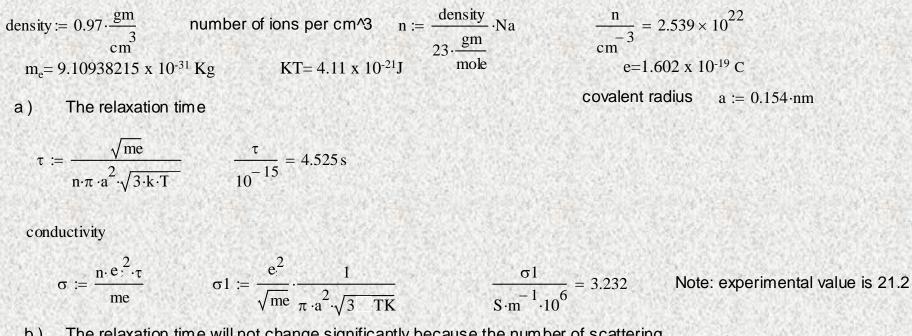
When J = 0 the drift velocity is zero. Meaning that in average each electron has zero displacement

When J \neq electron moves with typical velocity of v_{drift}

Electron moves in metal

Example 9.1

Calculate DC conductivity of Na at room temperature using Drude model. What would you expect the conductivity of Li to be if 10% of the Li were replaced by He?



b) The relaxation time will not change significantly because the number of scattering centers will remain. The electron concentration and the condcutivity will drop accordingly by 10%

Example 9.2

The Hall constant of silver is 1.19 times larger than theoretical $(R_h \cdot e \cdot n=1.19)$ and the plasma frequency is only 3.93 eV instead of the theoretical 8.98 eV.

a) What can you conclude about the real number of free electrons contributed by one atom?

b) Does the plasma frequency agree with Hall data? Can you offer a reasonable explanation?

$$R_{h} = \frac{1}{e \cdot n_{real}} \qquad \qquad \omega_{p} = e \cdot \sqrt{\frac{n_{real}}{m_{e} \cdot \varepsilon_{0}}}; E = \hbar \cdot \omega_{p}$$

1. Both number are hardly reconcilable. According to Hall effect $n_{nominal}/n_{real}=1.19$. n_{real} is smaller than $n_{nominal}$ by that factor of 1.19. According to the plasma frequency n_{real} is smaller than $n_{nominal}$ by a factor of $(8.93/3.93)^2=5$.

2. It is clear from the above that the only way how the numbers can agree with each other, is that the effective mass of the electron in Ag differs from the effective mass of a free electron, *i.e.* the band structure of Ag is quite complicated.

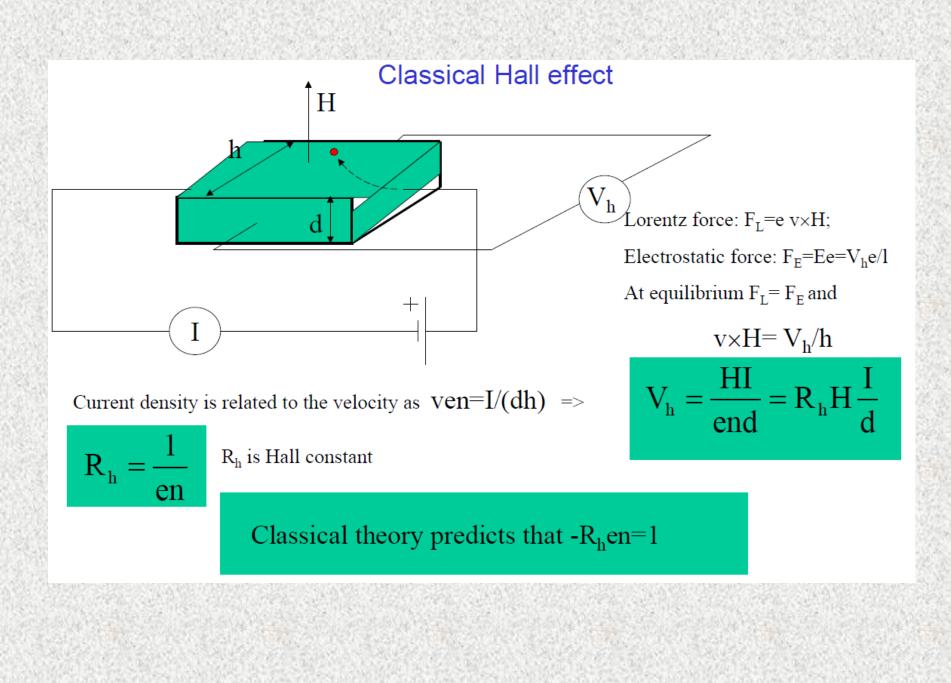


The resistivity of Cu is $1.7 \times 10^{-8} \Omega m$ at 300 K and the electron density is $8.5 \times 10^{28} m^{-3}$.

(a) Calculate the relaxation time of electrons in Cu at 300 K .(b) Calculate the mean free path of the electrons using Drude approximation.

a) $\tau := \frac{me}{\tau} = 2.46 \times 10^{-14} s$

b) Vther:=
$$\left(\frac{3 \cdot k \cdot T}{me}\right)^{\frac{1}{2}}$$
 Ither:= Vther τ $\frac{\text{ther}}{10^{-9} \cdot m} = 2.874$ nm



Example 9.4

Prove that the combination of Hall effect measurements and resitivity measurements permits determination of the electron relaxation time

$$R_{h} = \frac{1}{e \cdot n}$$

Hall voltage $V_{h} = R_{h} \cdot \frac{IH}{d} = \frac{H \cdot I}{e \cdot n \cdot d} \Longrightarrow n = \frac{H \cdot I}{e \cdot d \cdot V_{h}}$

Conductivity
$$\sigma = \frac{ne^2 \tau}{m_e} \Rightarrow \tau = \frac{m_e \sigma}{ne^2} = \frac{m_e \cdot \sigma \cdot d \cdot V_h}{H \cdot I \cdot e}$$